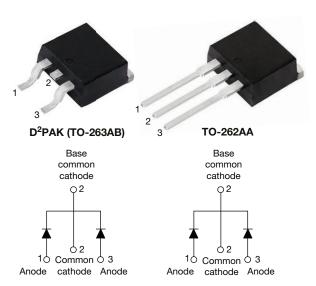
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High Performance Schottky Rectifier, 2 x 15 A



VS-32CTQ...S-M3

VS-32CTQ...-1-M3

PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 15 A						
V _R	25 V, 30 V						
V _F at I _F	0.40 V						
I _{RM} typ.	97 mA at 125°C						
T _J max.	150 °C						
E _{AS}	13 mJ						
Package	D ² PAK (TO-263AB), TO-262AA						
Circuit configuration	Common cathode						

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	BOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	30	A						
V _{RRM}		25, 30	V						
I _{FSM}	t _p = 5 μs sine	900	A						
V _F	15 A _{pk} , T _J = 125 °C	0.40	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-32CTQ025S-M3 VS-32CTQ025-1-M3	VS-32CTQ030S-M3 VS-32CTQ030-1-M3	UNITS				
Maximum DC reverse voltage	V _R	25	30	V				
Maximum working peak reverse voltage	V _{RWM}	25	30	v				

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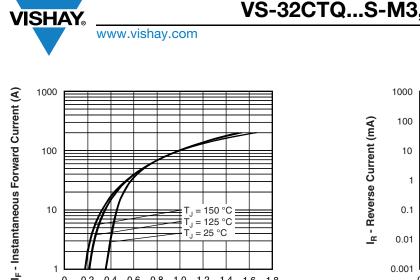
ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 115 °C	30					
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	900	А			
surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	250				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 1.20 \ A, \ L = 11$	13	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	3	А				

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST C	VALUES	UNITS				
Maximum forward voltage drop See fig. 1		15 A	T.I = 25 °C	0.49	V			
	V _{FM} ⁽¹⁾	30 A	1j=25 C	0.58				
	VFM (*)	15 A		0.40				
		30 A	1j=125 0	0.53				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm c} = {\rm Retad} V_{\rm c}$	1.75	m۸			
	IRM (")	T _J = 125 °C	V _R = Rated V _R	145	mA			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	97	mA			
Threshold voltage	V _{F(TO)}			0.233	V			
Forward slope resistance	r _t	ij = ij maximum	$T_J = T_J$ maximum		mΩ			
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal rar	1300	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/ _P						

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

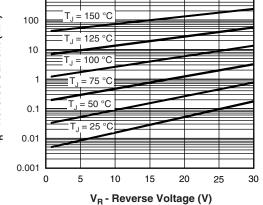
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10			
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torgue	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style D ² PAK (TO-263AB)	32CTQ025S				
			Case sivie D-PAK (10-263AB)	32CTC	2030S			
			Case at the TO 2624 A	32CTQ025-1				
			Case style TO-262AA	32CTC	32CTQ030-1			



1.6 1.8

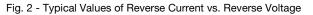
VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

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V_{FM} - Forward Voltage Drop (V) Fig. 1 - Maximum Forward Voltage Drop Characteristics

0 0.2 0.4 0.6 0.8 1.0 1.2 1.4



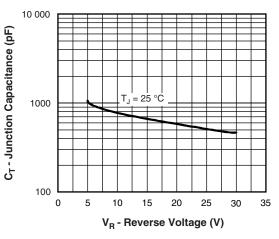


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

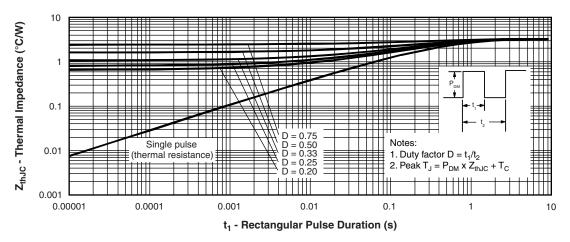
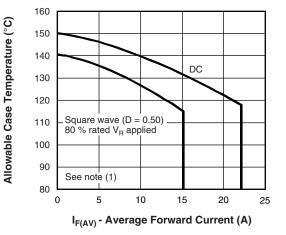


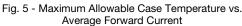
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

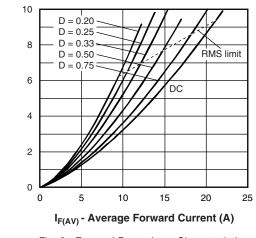
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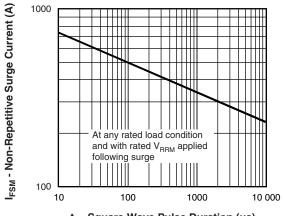
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Average Power Loss (W)

t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

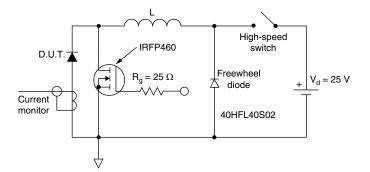


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{BEV} = inverse power loss = $V_{B1} \times I_B$ (1 - D); I_B at V_{B1} = 80 % rated V_B

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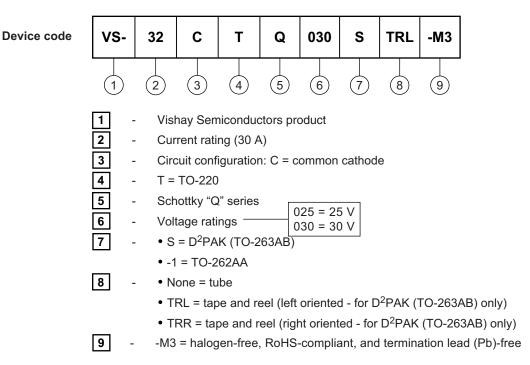


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ORDERING INFORMATION TABLE

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SHAY



ORDERING INFORMATION								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-32CTQ025S-M3	50	Antistatic plastic tubes						
VS-32CTQ025STRL-M3	800	13" diameter plastic tape and reel						
VS-32CTQ025STRR-M3	800	13" diameter plastic tape and reel						
VS-32CTQ030S-M3	50	Antistatic plastic tubes						
VS-32CTQ030STRL-M3	800	13" diameter plastic tape and reel						
VS-32CTQ030STRR-M3	800	13" diameter plastic tape and reel						
VS-32CTQ025-1-M3	50	Antistatic plastic tubes						
VS-32CTQ030-1-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
	TO-262AA	www.vishay.com/doc?96165					
Dant manification formation	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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Outline Dimensions



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TO-262

DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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